# RENESAS

### FOUR OUTPUT DIFFERENTIAL BUFFER FOR PCIE GEN1-3

### 9DB433

### Description

The 9DB433 zero-delay buffer supports PCIe Gen3 requirements, while being backwards compatible to PCIe Gen2 and Gen1. The 9DB433 is driven by a differential SRC output pair from an IDT 932S421 or 932SQ420 or equivalent main clock generator.

# **Typical Applications**

4 output PCIe Gen1-3 zero-delay/fanout buffer

# **Key Specifications**

- Output cycle-cycle jitter <50ps
- Output to Output skew <50ps
- Phase jitter: PCIe Gen3 <1.0ps rms

### **Features**

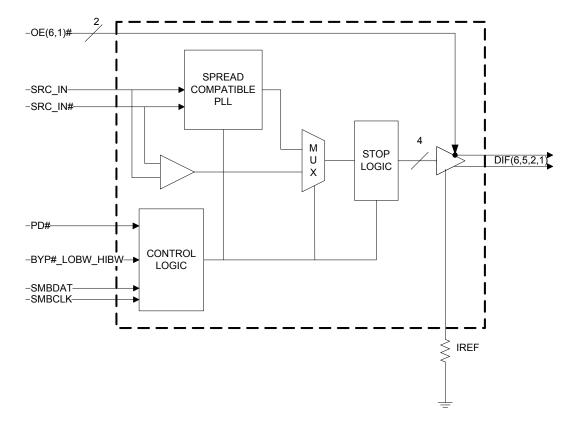
- 3 selectable SMBus addresses; multiple devices can share the same SMBus segment
- OE# pins; suitable for Express Card applications
- PLL or bypass mode; PLL can dejitter incoming clock
- Selectable PLL bandwidth; minimizes jitter peaking in downstream PLLs
- Spread spectrum compatible; tracks spreading input clock for low EMI
- SMBus interface; unused outputs can be disabled
- Supports undriven differential outputs in Power Down mode for power management

### **Output Features**

- 4 0.7V current-mode differential HCSL output pairs
- Supports zero delay buffer mode and fanout mode
- Selectable bandwidth

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- 50–110MHz operation in PLL mode
- 5-166MHz operation in Bypass mode



# Block Diagram

# **Pin Configuration**

#### Notes:

Highlighted Pins are the differences between 9DB403 and 9DB433.

Pin 12 and Pin 17 are latched on power up. Please make sure that the power supply to the pullup/pulldown resistors ramps at the same time as the main supply to the chip.

### **SMBus Address Selection and Readback**

SMB_ADR_tri	Address
Low	DA/DB
Mid	DC/DD
High	D8/D9

### PLL Operating Mode Readback Table

BYP#_LOBW_HIBW	MODE	Byte0, bit 3	Byte 0 bit 1
Low	Bypass	0	0
Mid	PLL 100M Hi BW	1	0
High	PLL 100M Low BW	0	1

### **Power Groups**

umber	- Description				
GND					
4	SRC_IN/SRC_IN#				
4	DIF(1,2,5,6)				
15	DIGITAL VDD/GND				
27	Analog VDD/GND for PLL in IREF				
	GND 4 4 15				

### **Tri-Level Input Logic Pins**

State of Pin	Voltage
Low	<0.8V
Mid	1.2 <vin<1.8v< th=""></vin<1.8v<>
High	Vin > 2.0V

For best results, treat pin 1 as analog VDD.

# **Pin Descriptions**

PIN #	PIN NAME	<b>PIN TYPE</b>	DESCRIPTION
1	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an
I	VUUN	FVN	analog power rail and filtered appropriately.
2	SRC_IN	IN	0.7 V Differential SRC TRUE input
3	SRC_IN#	IN	0.7 V Differential SRC COMPLEMENTARY input
4	GND	PWR	Ground pin.
5	VDD	PWR	Power supply, nominal 3.3V
6	DIF_1	OUT	0.7V differential true clock output
7	DIF_1#	OUT	0.7V differential Complementary clock output
8	OE1#	IN	Active low input for enabling DIF pair 1.
0	OE1#		1 =disable outputs, 0 = enable outputs
9	DIF_2	OUT	0.7V differential true clock output
10	DIF_2#	OUT	0.7V differential Complementary clock output
11	VDD	PWR	Power supply, nominal 3.3V
12	BYP#_HIBW_LOBW	IN	Tri-level input to select bypass mode, Hi BW PLL, or Lo BW PLL mode
13	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
14	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
15	GND	PWR	Ground pin.
16	VDD	PWR	Power supply, nominal 3.3V
17	SMB_ADR_tri	IN	SMBus address select bit. This is a tri-level input that decodes 1 of 3 SMBus Addresses.
18	VDD	PWR	Power supply, nominal 3.3V
18	DIF_5#	OUT	0.7V differential Complementary clock output
20	DIF_5	OUT	0.7V differential true clock output
20		001	Active low input for enabling DIF pair 6.
21	OE6#	IN	1 =disable outputs, $0$ = enable outputs
22	DIF_6#	OUT	0.7V differential Complementary clock output
22	DIF_6	OUT	0.7V differential complementary clock output
23	VDD	PWR	Power supply, nominal 3.3V
24			Asynchronous active low input pin used to power down the device. The internal
25	PD#	IN	clocks are disabled and the VCO and the crystal osc. (if any) are stopped.
			This pin establishes the reference for the differential current-mode output pairs. It
00			requires a fixed precision resistor to ground. 475ohm is the standard value for
26	IREF	OUT	100ohm differential impedance. Other impedances require different values. See data
			sheet.
27	GNDA	PWR	Ground pin for the PLL core.
28	VDDA	PWR	3.3V power for the PLL core.

# **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the 9DB433. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
3.3V Core Supply Voltage	VDDA/R				4.6	V	1,2
3.3V Logic Supply Voltage	VDD				4.6	V	1,2
Input Low Voltage	V <sub>IL</sub>		GND-0.5			V	1
Input High Voltage	V <sub>IH</sub>	Except for SMBus interface			$V_{DD}$ +0.5V	V	1
Input High Voltage	VIHSMB	SMBus clock and data pins			5.5V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

# **Electrical Characteristics–DIF 0.7V Current Mode Differential Outputs**

 $T_A = T_{COM}$  or  $T_{IND}$ ; Supply Voltage VDD = 3.3 V +/-5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on	1.5	2.8	4	V/ns	1, 2, 3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		8	20	%	1, 2, 4
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	797	850	mV	1
Voltage Low	VLow	averaging on)		14	150	IIIV	1
Max Voltage	Vmax	Measurement on single ended signal using		813	1150	mV	1
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-1		mv	1
Vswing	Vswing	Scope averaging off (Differential)	300	1596.9		mV	1, 2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	378	550	mV	1, 5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		16	140	mV	1, 6

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production. IREF = VDD/(3xR<sub>R</sub>). For R<sub>R</sub> = 475 $\Omega$  (1%), I<sub>REF</sub> = 2.32mA. I<sub>OH</sub> = 6 x I<sub>REF</sub> and V<sub>OH</sub> = 0.7V @ Z<sub>O</sub>=50 $\Omega$  (100 $\Omega$  differential impedance).

<sup>2</sup> Measured from differential waveform

<sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of V\_cross\_min/max (V\_cross absolute) allowed. The intent is to limit Vcross induced modulation by setting V\_cross\_delta to be smaller than V\_cross absolute.

# **Electrical Characteristics–Input/Supply/Common Parameters**

$TA = T_{abs} or T_{abs}$	Supply Voltage VDI	) – 3 3 V ±/-5%
IA = ICOM UIIIND	Supply vollage vD	J = 3.3 V + 7.5 / 6

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating	Т <sub>СОМ</sub>	Commercial range	0		70	°C	1
Temperature	T <sub>IND</sub>	Industrial range	-40		85	°C	1
Input High Voltage	V <sub>IH</sub>	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V <sub>DD</sub> + 0.3	v	1
Input Low Voltage	V <sub>IL</sub>	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	v	1
	I <sub>IN</sub>	Single-ended inputs, $V_{IN} = GND$ , $V_{IN} = VDD$	-5	-0.02	5	uA	1
Input Current	I <sub>INP</sub>	Single-ended inputs $V_{IN} = 0 \text{ V}$ ; Inputs with internal pull-up resistors $V_{IN} = \text{VDD}$ ; Inputs with internal pull-down resistors	-50		50	uA	1
Input Frequency	F <sub>ibyp</sub>	$V_{DD} = 3.3 V$ , Bypass mode	5		166	MHz	2
Input Frequency	F <sub>ipll</sub>	$V_{DD} = 3.3 \text{ V}, 100 \text{MHz PLL} \text{ mode}$	50	100	110	MHz	2
Pin Inductance	L <sub>pin</sub>				7	nH	1
	CIN	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	$C_{INDIF_IN}$	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	Cour	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From $V_{DD}$ Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation Frequency	f <sub>MODIN</sub>	Allowable Frequency (Triangular Modulation)	30	31.5	33	kHz	1
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	1	2	3	cycles	1,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion		13	300	us	1,3
Tfall	t <sub>F</sub>	Fall time of control inputs			5	ns	1,2
Trise	t <sub>R</sub>	Rise time of control inputs			5	ns	1,2
SMBus Input Low Voltage	VILSMB				0.8	V	1
SMBus Input High Voltage	VIHSMB		2.1		V <sub>DDSMB</sub>	V	1
SMBus Output Low Voltage	V <sub>OLSMB</sub>	@ I <sub>PULLUP</sub>			0.4	V	1
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	1
Nominal Bus Voltage	V <sub>DDSMB</sub>	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			440	kHz	1,5

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Control input must be monotonic from 20% to 80% of input swing.

 $^3$  Time from deassertion until outputs are >200 mV.

<sup>4</sup> DIF\_IN input.

<sup>5</sup> The differential input clock must be running for the SMBus to be active.

# **Electrical Characteristics–DIF\_IN Clock Input Parameters**

T<sub>AMB</sub>=T<sub>COM</sub> or T<sub>IND</sub> unless otherwise indicated, supply voltages per normal operation conditions; see Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V <sub>CROSS</sub>	Cross Over Voltage	150	375	900	mV	1
Input Swing - DIF_IN	V <sub>SWING</sub>	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.6		8	V/ns	1,2
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{DD}, V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d <sub>tin</sub>	Measurement from differential waveform	45		55	%	1
Input Jitter - Cycle to Cycle	$J_{DIFIn}$	Differential measurement	0		125	ps	1

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Slew rate measured through +/-75mV window centered around differential zero.

# **Electrical Characteristics–Current Consumption**

TA =  $T_{COM}$  or  $T_{IND}$ ; Supply Voltage VDD = 3.3 V +/-5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	МАХ	UNITS	NOTES
Operating Supply Current	I <sub>DD3.3OP</sub>	All outputs active @100MHz, C <sub>L</sub> = Full load;		93	120	mA	1
Bowordown Current	I <sub>DD3.3PD</sub>	All diff pairs driven		30	40	mA	1
Powerdown Current	I <sub>DD3.3PDZ</sub>	All differential pairs tri-stated		3	6	mA	1

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

### Electrical Characteristics–Output Duty Cycle, Jitter, Skew and PLL Characteristics

#### TA = T<sub>COM</sub> or T<sub>IND;</sub> Supply Voltage VDD = 3.3 V + -5%

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
		-3dB point in High BW Mode (T <sub>IND</sub> )		2.8	4.1	MHz	1
PLL Bandwidth	BW	-3dB point in High BW Mode (T <sub>COM</sub> )	2	2.8	4	MHz	1
		-3dB point in Low BW Mode	0.7	1.1	1.4	MHz	1
PLL Jitter Peaking	t <sub>JPEAK</sub>	Peak Pass band Gain		1.5	2	dB	1
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	49.2	55	%	1
Duty Cycle Distortion	t <sub>DCD</sub>	Measured differentially, Bypass Mode @100MHz	-2	-0.4	2	%	1,4
		Bypass Mode, V <sub>T</sub> = 50% (T <sub>IND</sub> )	3500	4263	4900	ps	1
Skew, Input to Output	t <sub>pdBYP</sub>	Bypass Mode, V <sub>T</sub> = 50% (T <sub>COM</sub> )	3500	4115	4500	ps	1,5
	t <sub>pdPLL</sub>	PLL Mode V <sub>T</sub> = 50%	-250	-45	250	ps	1
Skew, Output to Output	t <sub>sk3</sub>	V <sub>T</sub> = 50%		40.0	50/60	ps	1,5
Jitter, Cycle to cycle	+	PLL mode		21	50	ps	1,3
	t <sub>jcyc-cyc</sub>	Additive Jitter in Bypass Mode		3	10	ps	1,3

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

 $^{2}$  I<sub>REF</sub> = V<sub>DD</sub>/(3xR<sub>R</sub>). For R<sub>R</sub> = 475 $\Omega$  (1%), I<sub>REF</sub> = 2.32mA. I<sub>OH</sub> = 6 x I<sub>REF</sub> and V<sub>OH</sub> = 0.7V @ Z<sub>O</sub>=50 $\Omega$ .

<sup>3</sup> Measured from differential waveform

<sup>4</sup> Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

<sup>5</sup> First number is commercial temp, second number is industrial temp.

# **Electrical Characteristics–PCIe Phase Jitter Parameters**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
	t <sub>jphPCleG1</sub>	PCle Gen 1		26	40	86	ps (p-p)	1,2,3
Dhace litter DLL Made		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.8	1.2	3	ps (rms)	1,2
Phase Jitter, PLL Mode	t <sub>jphPCleG2</sub>	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		1.6	1.8	3.1	ps (rms)	1,2
	t <sub>jphPCleG3</sub>	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.48	0.6	1	ps (rms)	1,2,4
	t <sub>jphPCleG1</sub>	PCle Gen 1		2.6	5	N/A	ps (p-p)	1,2,3
Additive Phase Jitter,	t <sub>jphPCleG2</sub>	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.06	0.2	N/A	ps (rms)	1,2
Bypass Mode		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)			0.3	N/A	ps (rms)	1,2
	t <sub>jphPCleG3</sub>	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)			0.1	N/A	ps (rms)	1,2

<sup>1</sup> Applies to all outputs.

<sup>2</sup> See http://www.pcisig.com for complete specs

<sup>3</sup> Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

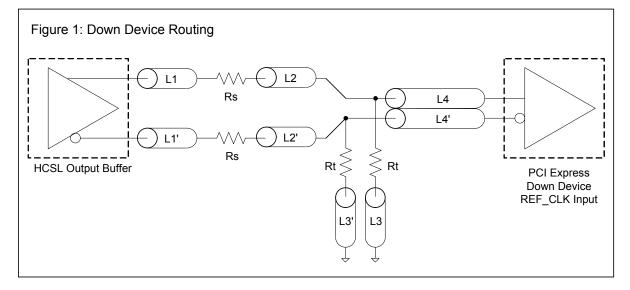
# **Clock Periods–Differential Outputs Tracking Spread Spectrum**

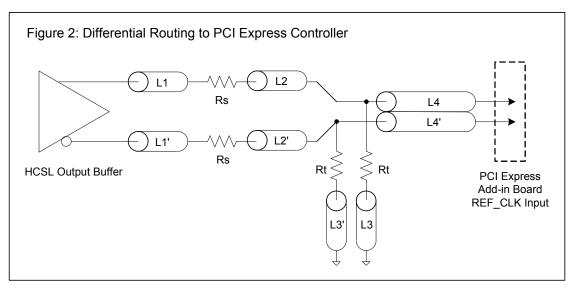
Measurement									
Window	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
Symbol	Lg-	-SSC	-ppm error	0ppm	+ ppm error	+SSC	Lg+		
Definikien	Absolute Period	Short-term Average	Long-Term Average	Period	Long-Term Average	Short-term Average	Period		
Definition	Minimum Absolute	Minimum Absolute	Minimum Absolute	Nominal	Maximum	Maximum	Maximum		
	Period	Period	Period					Units	Notes
DIF 100	9.949	9.999	10.024	10.025	10.026	10.051	10.101	ns	1,2,3

Output Termination and Layout Information					
Common Recommendations for Differential Routing	Dimension or Value	Unit	Figure		
L1 length, route as non-coupled 50ohm trace	0.5 max	inch	1		
L2 length, route as non-coupled 50ohm trace	0.2 max	inch	1		
L3 length, route as non-coupled 50ohm trace	0.2 max	inch	1		
Rs	33	ohm	1		
Rt	49.9	ohm	1		

Down Device Differential Routing			
L4 length, route as coupled microstrip 100ohm differential trace	2 min to 16 max	inch	1
L4 length, route as coupled stripline 100ohm differential trace	1.8 min to 14.4 max	inch	1

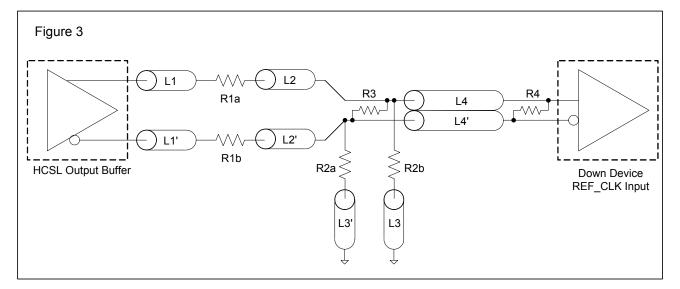
Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace	0.25 to 14 max	inch	2
L4 length, route as coupled stripline 100ohm differential trace	0.225 min to 12.6 max	inch	2



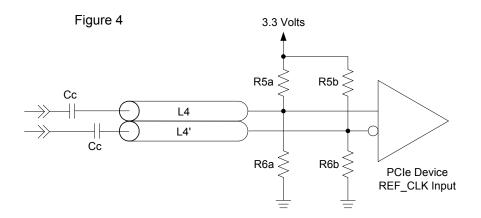


	Termination for LVDS and other Common Differential Signals (figure 3)						
Vdiff	Vp-р	Vcm	R1	R2	R3	R4	Note
0.45v	0.22v	1.08	33	150	100	100	
0.58	0.28	0.6	33	78.7	137	100	
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible
0.60	0.3	1.2	33	174	140	100	Standard LVDS
R1a = R	1b = R1	-	-			-	-

R2a = R2b = R2



Termination for Cable AC Coupled Application (figure 4)					
Component	Value	Note			
R5a, R5b	8.2K 5%				
R6a, R6b	1K 5%				
Сс	0.1 µF				
Vcm	0.350 volts				



# **General SMBus Serial Interface Information for 9DB433**

### How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- · Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Co	ntroller (Host)		IDT (Slave/Receiver
Т	starT bit	1	
S	lave Address	-	
WR	WRite		
			ACK
Beg	inning Byte = N		
			ACK
RT	Repeat starT		
S	lave Address		
RD	ReaD		
		_	ACK
		-	Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ę	0
0		X Byte	0
0		<b>×</b>	0
	0	_	
	1		Byte N + X - 1
Ν	Not acknowledge	_	
Р	stoP bit		

Index Block Write Operation					
Control	ler (Host)		IDT (Slave/Receiver)		
Т	starT bit				
Slave	Address				
WR	WRite				
			ACK		
Beginnin	g Byte = N				
			ACK		
Data Byte	Count = X				
			ACK		
Beginnir	ng Byte N				
			ACK		
0		×			
0		X Byte	0		
0		Ō	0		
			0		
Byte N	l + X - 1				
			ACK		
Р	stoP bit				

Read Address	Write Address
DD* <sub>(H)</sub>	DC* <sub>(H)</sub>

\*Assuming SMB\_ADR\_tri is at mid-level

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### SMBus Table: Frequency Select Register, READ/WRITE ADDRESS (Selectable)

Byt	te 0	Pin #	Name	Control Function	Туре	0	1	Default	
Bit 7		-	PD_Mode	PD# drive mode	RW	driven	Hi-Z	1	
Bit 6		-	OE_Mode	OE#_Stop drive mode	RW	driven	Hi-Z	0	
Bit 5		-		Reserved				0	
Bit 4		-		Reserved					
Bit 3		-	MODE1	BYPASS#/PLL1	RW	See Operating Mode Readback Table		Latched	
Bit 2		-		Reserved				1	
Bit 1		-	MODE0	BYPASS#/PLL0	RW	See Operating Mode Readback Table		Latched	
Bit 0		-	SRC_DIV#	SRC Divide by 2 Select	RW	x/2	x/1	1	

### SMBus Table: Output Control Register

Byt	te 1	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				1
Bit 6	22	2,23	DIF_6	Output Enable	RW	Disable	Enable	1
Bit 5	19	9,20	DIF_5	Output Enable	RW	Disable	Enable	1
Bit 4		Reserved					1	
Bit 3				Reserved				1
Bit 2	9	,10	DIF_2	Output Enable	RW	Disable	Enable	1
Bit 1	6	6,7	DIF_1	Output Enable	RW	Disable	Enable	1
Bit 0				Reserved				1

NOTE: The SMBus Output Enable Bit must be '1' AND the respective OE pin must be active for the output to run!

### SMBus Table: OE Pin Control Register

Byt	te 2	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				0
Bit 6	22	2,23	DIF_6	DIF_6 Stoppable with OE6#	RW	Free-run	Stoppable	0
Bit 5	19	9,20	DIF_5	DIF_5 Stoppable with OE5#	RW	Free-run	Stoppable	0
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2	9	,10	DIF_2	DIF_2 Stoppable with OE2#	RW	Free-run	Stoppable	0
Bit 1	6	6,7	DIF_1	DIF_1 Stoppable with OE1#	RW	Free-run	Stoppable	0
Bit 0				Reserved				0

NOTE: Only OE1# and OE6# are available on 28-TSSOP/SSOP packages. If you wish the default to be "Stoppable" see the 9DB434.

#### **SMBus Table: Reserved Register**

By	te 3	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				Х
Bit 6				Reserved				Х
Bit 5				Reserved				
Bit 4				Reserved				Х
Bit 3				Reserved				Х
Bit 2				Reserved				Х
Bit 1				Reserved				Х
Bit 0				Reserved				Х

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Byt	te 4	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7		-	RID3		R	-	-	0
Bit 6		-	RID2	REVISION ID	R	-	-	0
Bit 5		-	RID1		R	-	-	0
Bit 4		-	RID0		R	-	-	1
Bit 3		-	VID3		R	-	-	0
Bit 2		-	VID2		R	-	-	0
Bit 1		-	VID1	VENDOR ID	R	-	-	0
Bit 0		-	VID0		R	-	-	1

### SMBus Table: Vendor & Revision ID Register

#### SMBus Table: DEVICE ID

By	te 5 Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	DID7	Device ID 7 (MSB)	R			0
Bit 6	-	DID6	Device ID 6	R			1
Bit 5	-	DID5	Device ID 5	R			0
Bit 4	-	DID4	Device ID 4	R	Device ID is	3 43 Hex for	0
Bit 3	-	DID3	Device ID 3	R	9DE	3433	0
Bit 2	-	DID2	Device ID 2	R			0
Bit 1	-	DID1	Device ID 1	R	]		1
Bit 0	-	DID0	Device ID 0	R			1

### SMBus Table: Byte Count Register

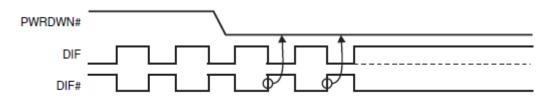
By	te 6	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7		-	BC7		RW	-	-	0
Bit 6		-	BC6		RW	-	-	0
Bit 5		-	BC5		RW	-	-	0
Bit 4		-	BC4	Writing to this register configures how	RW	-	-	0
Bit 3		-	BC3	many bytes will be read back.	RW	-	-	0
Bit 2		-	BC2		RW	-	-	1
Bit 1		-	BC1		RW	-	-	1
Bit 0		-	BC0		RW	-	-	1

### PD#, Power Down

The PD# pin cleanly shuts off all clocks and places the device into a power saving mode. PD# must be asserted before shutting off the input clock or power to insure an orderly shutdown. PD is asynchronous active-low input for both powering down the device and powering up the device. When PD# is asserted, all clocks will be driven high, or tri-stated (depending on the PD# drive mode and Output control bits) before the PLL is shut down.

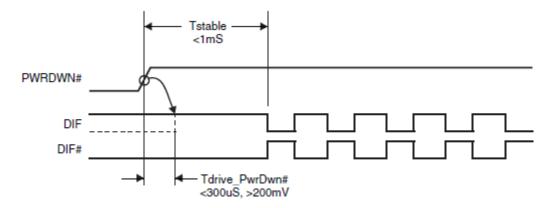
### **PD# Assertion**

When PD# is sampled low by two consecutive rising edges of DIF#, all DIF outputs must be held High, or tri-stated (depending on the PD# drive mode and Output control bits) on the next High-Low transition of the DIF# outputs. When the PD# drive mode bit is set to '0', all clock outputs will be held with DIF driven High with 2 x IREF and DIF# tri-stated. If the PD# drive mode bit is set to '1', both DIF and DIF# are tri-stated.

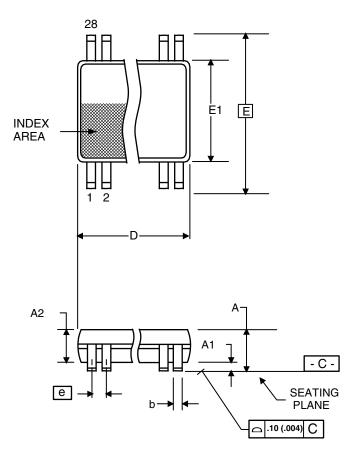


### **PD# De-assertion**

Power-up latency is less than 1 ms. This is the time from de-assertion of the PD# pin, or VDD reaching 3.3V, or the time from valid SRC\_IN clocks until the time that stable clocks are output from the device (PLL Locked). If the PD# drive mode bit is set to '1', all the DIF outputs must driven to a voltage of >200mV within 300µs of PD# de-assertion.



# Package Outline Drawings (28-pin SSOP)

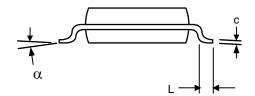


		209 mil SSC	OP		
	In Mil	limeters	In Inches		
SYMBOL	COMMON [	DIMENSIONS	COMMON [	DIMENSIONS	
	MIN	MAX	MIN	MAX	
A		2.00		.079	
A1	0.05		.002		
A2	1.65	1.85	.065	.073	
b	0.22	0.38	.009	.015	
С	0.09	0.25	.0035	.010	
D	SEE VA	RIATIONS	SEE VARIATIONS		
E	7.40	8.20	.291	.323	
E1	5.00	5.60	.197	.220	
е	0.65	BASIC	0.0256	6 BASIC	
L	0.55	0.95	.022	.037	
N	SEE VA	RIATIONS	SEE VARIATIONS		
α	0°	8°	0°	8°	

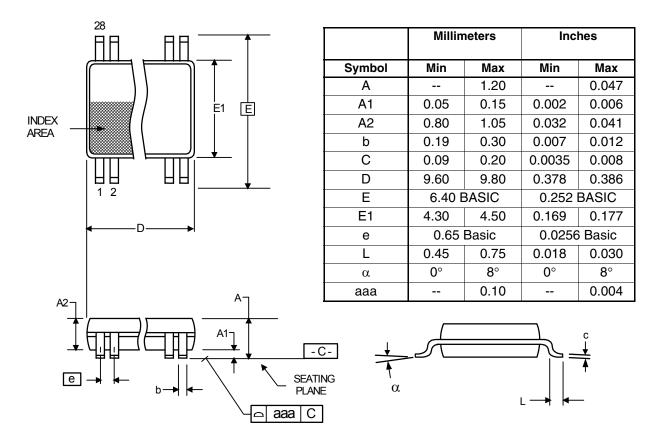
VARIATIONS

N	D	mm.	D (	inch)
IN	MIN	MAX	MIN	MAX
28	9.90	10.50	.390	.413

Reference Doc.: JEDEC Publication 95, MO-150



# Package Outline Drawings (28-pin TSSOP)



# **Ordering Information**

Part / Order Number	Shipping Packaging	Package	Temperature
9DB433AFLF	Tubes	28-pin SSOP	0 to +70°C
9DB433AFLFT	Tape and Reel	28-pin SSOP	0 to +70°C
9DB433AGLF	Tubes	28-pin TSSOP	0 to +70°C
9DB433AGLFT	Tape and Reel	28-pin TSSOP	0 to +70°C
9DB433AFILF	Tubes	28-pin SSOP	-40 to +85°C
9DB433AFILFT	Tape and Reel	28-pin SSOP	-40 to +85°C
9DB433AGILF	Tubes	28-pin TSSOP	-40 to +85°C
9DB433AGILFT	Tape and Reel	28-pin TSSOP	-40 to +85°C

"LF" suffix to the part number denotes Pb-Free configuration, RoHS compliant.

"A" is the device revision designator (will not correlate with the datasheet revision).

### **Revision History**

Issue Date	Description	Page #			
6/30/2010	Released to final				
	1. Update pin 1 pin-name and pin description from VDD to VDDR. This highlights that optimal				
	performance is obtained by treating VDDR as in analog pin. This is a document update only,				
5/9/2011	there is no silicon change.	Various			
	1. Added additional line to PLL Bandwidth "-3dB point in High BW Mode" conditions for				
3/13/2012	industrial mode (min1.5, typ 2.7, max 4.1 MHz)	6			
	2. Added additional line to Skew, Input to Output "Bypass Mode" conditions for industrial				
	mode (min 2500, max 4900 ps)				
7/5/2012	1. Changed references of PCIe Gen3 to PCIe Gen1,2,3	1			
7/12/2012	1. Added missing typical values to DS.	Various			
	Updated Byte 2, bits 1, 2, 5 and 6 per char review. Outputs can be programmed with Byte 2	Various			
9/10/2012	to be Stoppable or Free-Run with DIF_Stop pin, not the OE pins.	vanous			
9/30/2013	Corrected typo in ordering information for 28-SSOP I-temp device.	15			
8/14/2015	1. Corrected default value of Byte 2 to 00hex. Added note referring to 9DB434 if FFhex is	11			
0/14/2013	the desired default.	11			
	1. Corrected Idd values for 9DB433.				
	2. Updated typical values in electrical tables.				
6/7/2016	3. Updated clock input electrical table to latest format.	Various			
	4. Updated SMbus operating frequency to 440KHz.				
	5. Corrected typo in Byte 0, bit 6 defaults to 0.				
5/25/2018	1. Updated the minimum input slew rate from 1 V/ns to 0.6V/ns.	6			

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